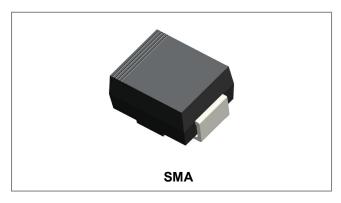






SK310A SCHOTTKY RECTIFIER



Features

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term
- reliability
- Green products in compliance the ROHS directive
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _L =100°C, rectangular wave form	3	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	110	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.77	0.85	V
	V _{F1}	@ 3A, Pulse, T _J = 125 °C	0.62	0.80	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_{R_1} T_J = 25 ^{\circ}\text{C}$	0.001	0.6	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	1	20.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	120	250	pF
Series Inductance	L _S	Measured lead to lead 5 mm from package body 8.0		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

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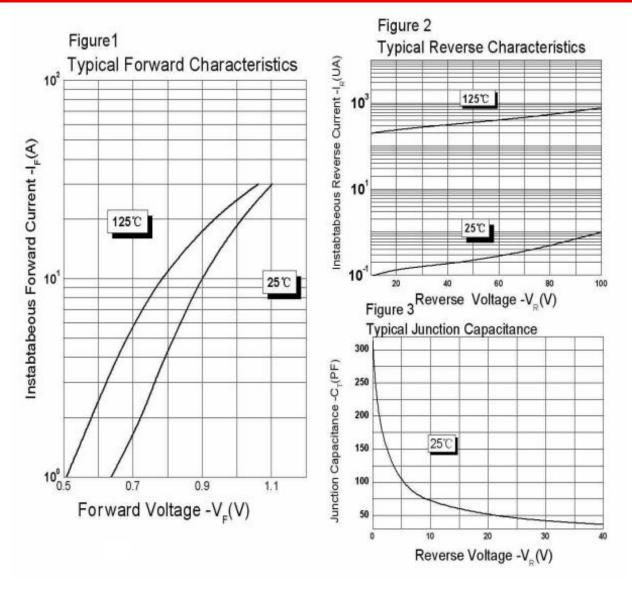




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	R _θ JL	DC operation	20	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	77	°C/W
Approximate Weight	wt	-	0.06	g

Ratings and Characteristics Curves



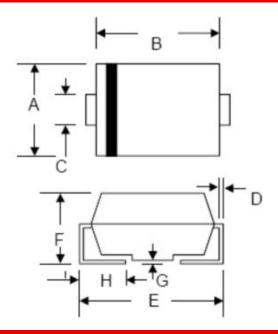
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Mechanical Dimensions SMA



SYMBOL	Millimeters		Inches		
STIVIBUL	Min.	Max.	Min.	Max.	
Α	2.40	2.84	0.094	0.112	
В	3.99	4.75	0.157	0.187	
С	1.05	1.70	0.041	0.067	
D	0.15	0.51	0.006	0.020	
Е	4.80	5.66	0.189	0.223	
F	1.90	2.95	0.075	0.116	
G	0.05	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.600	

Ordering Information

Device	Package	Shipping
SK310A	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



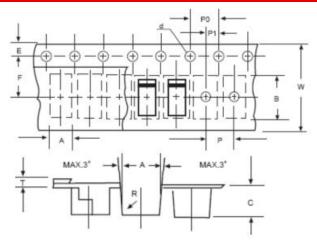
Where XXXXX is YYWWL

A = Package type
3 = Forward Current (3A)
10 = Reverse Voltage (100V)
YY = Year

WW = Year Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape & Reel Specification SMA



SYMBOL	Millimeters		
	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
Е	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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